## Atomistic observation of the lithiation and delithiation behaviors of silicon nanowires using reactive molecular dynamics simulations

## <u>Sang Soo Han</u><sup>1,\*</sup>, Hyun Jung<sup>1,2</sup>, Minho Lee<sup>1</sup>, Byung Chul Yeo<sup>1</sup>, Kwang Ryeol Lee<sup>1</sup> <sup>1</sup>KIST; <sup>2</sup>Hanyang University (sangsoo@kist.re.kr<sup>\*</sup>)

In this talk, we will discuss the mechanisms for the lithiation and delithiation of Si NWs determined using a large-scale molecular dynamics (MD) simulation with a reactive force field (ReaxFF). The ReaxFF is developed using results from first-principles calculations for various crystals and molecules. During the lithiation process, Li atoms penetrate into the lattices of the crystalline Si (*c*-Si) NWs preferentially along the <110> or <112> direction, and then the c-Si changes into amorphous  $Li_xSi$  (a -Li\_xSi) phases due to the simultaneous breaking of Si -Si bonds as a result of the tensile stresses between Si atoms. Before the complete amorphization of the Si NWs, we observe the formation of silicene -like structures in the NWs that are eventually broken into low -coordinated components, such as dumbbells and isolated atoms. Additionally, during delithiation of  $Li_xSi$  NWs, we observe the formation of a small amount of c -Si nuclei in the a -Li\_xSi matrix below a composition of  $Li_{1.4}Si \sim Li_{1.5}Si$ , and we demonstrate that the two phase structure can be thermodynamically more favorable than the single-phase a -Li\_xSi.